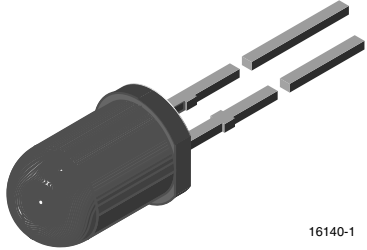


## Silicon PIN Photodiode, RoHS Compliant



16140-1

### DESCRIPTION

BPV10NF is a PIN photodiode with high speed and high radiant sensitivity in black, T-1 $\frac{3}{4}$  plastic package with daylight blocking filter. Filter bandwidth is matched with 870 nm to 950 nm IR emitters.

### FEATURES

- Package type: leaded
- Package form: T-1 $\frac{3}{4}$
- Dimensions (in mm):  $\varnothing$  5
- Leads with stand-off
- Radiant sensitive area (in mm<sup>2</sup>): 0.78
- High radiant sensitivity
- Daylight blocking filter matched with 870 nm to 950 nm emitters
- High bandwidth: > 100 MHz at  $V_R = 12$  V
- Fast response times
- Angle of half sensitivity:  $\varphi = \pm 20^\circ$
- Lead (Pb)-free component in accordance with RoHS 2002/95/EC and WEEE 2002/96/EC



**RoHS**  
COMPLIANT

### APPLICATIONS

- High speed detector for infrared radiation
- Infrared remote control and free air data transmission systems, e.g. in combination with TSFFxxxx series IR emitters

PRODUCT SUMMARY			
COMPONENT	$I_{ra}$ (mA)	$\varphi$ (deg)	$\lambda_{0.5}$ (nm)
BPV10NF	60	$\pm 20$	790 to 1050

**Note**

Test condition see table "Basic Characteristics"

ORDERING INFORMATION			
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
BPV10NF	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1 $\frac{3}{4}$

**Note**

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		$V_R$	60	V
Power dissipation	$T_{amb} \leq 25^\circ\text{C}$	$P_V$	215	mW
Junction temperature		$T_j$	100	$^\circ\text{C}$
Operating temperature range		$T_{amb}$	- 40 to + 100	$^\circ\text{C}$
Storage temperature range		$T_{stg}$	- 40 to + 100	$^\circ\text{C}$
Soldering temperature	$t \leq 5$ s, 2 mm from body	$T_{sd}$	260	$^\circ\text{C}$
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm <sup>2</sup>	$R_{thJA}$	350	K/W

**Note**

$T_{amb} = 25^\circ\text{C}$ , unless otherwise specified

BASIC CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 50 \text{ mA}$	$V_F$		1.0	1.3	V
Breakdown voltage	$I_R = 100 \text{ }\mu\text{A}, E = 0$	$V_{(BR)}$	60			V
Reverse dark current	$V_R = 20 \text{ V}, E = 0$	$I_{ro}$		1	5	nA
Diode capacitance	$V_R = 0 \text{ V}, f = 1 \text{ MHz}, E = 0$	$C_D$		11		pF
Open circuit voltage	$E_e = 1 \text{ mW/cm}^2, \lambda = 870 \text{ nm}$	$V_O$		450		mV
Short circuit current	$E_e = 1 \text{ mW/cm}^2, \lambda = 870 \text{ nm}$	$I_K$		50		$\mu\text{A}$
Reverse light current	$E_e = 1 \text{ mW/cm}^2, \lambda = 870 \text{ nm}, V_R = 5 \text{ V}$	$I_{ra}$		55		$\mu\text{A}$
	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}, V_R = 5 \text{ V}$	$I_{ra}$	30	60		$\mu\text{A}$
Temperature coefficient of $I_{ra}$	$E_e = 1 \text{ mW/cm}^2, \lambda = 870 \text{ nm}, V_R = 5 \text{ V}$	$TK_{I_{ra}}$		-0.1		%/K
Absolute spectral sensitivity	$V_R = 5 \text{ V}, \lambda = 870 \text{ nm}$	$s(\lambda)$		0.55		A/W
Angle of half sensitivity		$\phi$		$\pm 20$		deg
Wavelength of peak sensitivity		$\lambda_p$		940		nm
Range of spectral bandwidth		$\lambda_{0.5}$		790 to 1050		nm
Quantum efficiency	$\lambda = 950 \text{ nm}$	$\eta$		70		%
Noise equivalent power	$V_R = 20 \text{ V}, \lambda = 950 \text{ nm}$	NEP		$3 \times 10^{-14}$		W/ $\sqrt{\text{Hz}}$
Detectivity	$V_R = 20 \text{ V}, \lambda = 950 \text{ nm}$	$D^*$		$3 \times 10^{12}$		$\text{cm}^2\sqrt{\text{Hz}}/\text{W}$
Rise time	$V_R = 50 \text{ V}, R_L = 50 \text{ }\Omega, \lambda = 820 \text{ nm}$	$t_r$		2.5		ns
Fall time	$V_R = 50 \text{ V}, R_L = 50 \text{ }\Omega, \lambda = 820 \text{ nm}$	$t_f$		2.5		ns

**Note**

$T_{amb} = 25 \text{ }^\circ\text{C}$ , unless otherwise specified

**BASIC CHARACTERISTICS**

$T_{amb} = 25 \text{ }^\circ\text{C}$ , unless otherwise specified

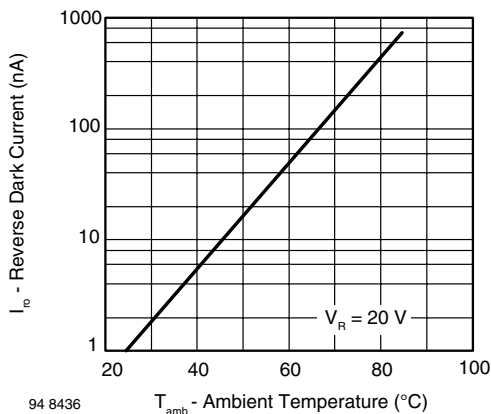


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

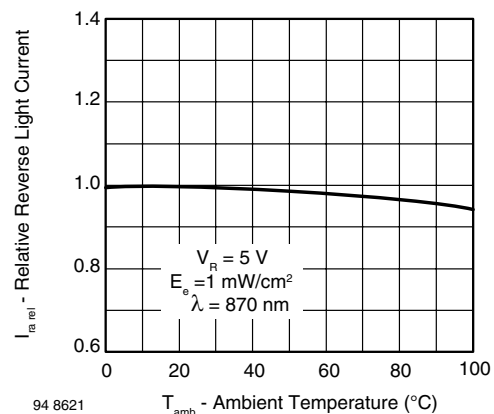


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

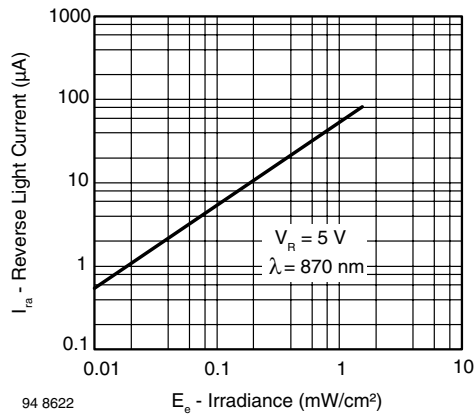


Fig. 3 - Reverse Light Current vs. Irradiance

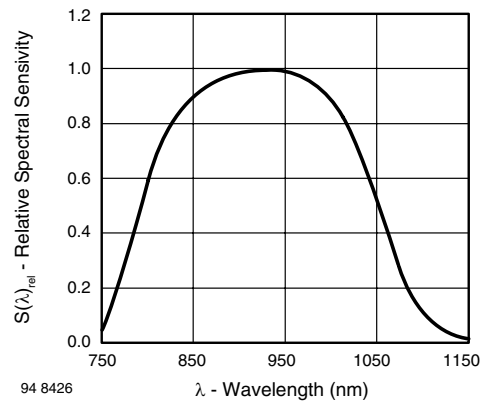


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

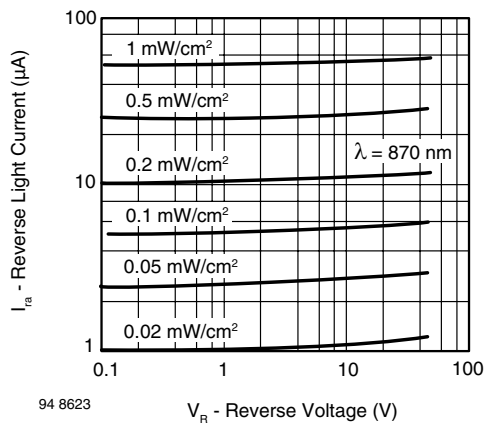


Fig. 4 - Reverse Light Current vs. Reverse Voltage

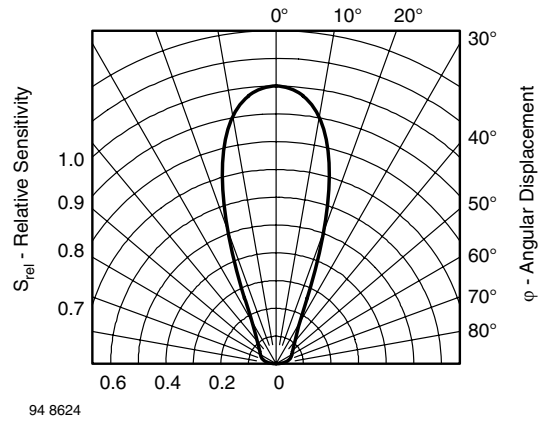


Fig. 7 - Relative Radiant Sensitivity vs. Angular Displacement

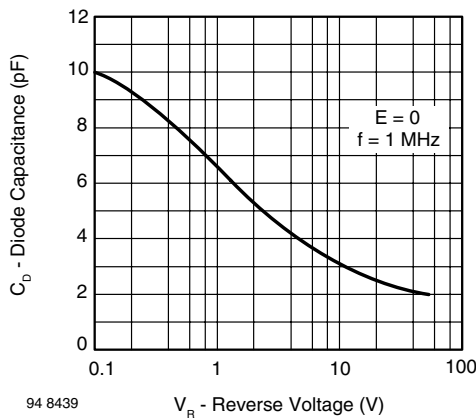
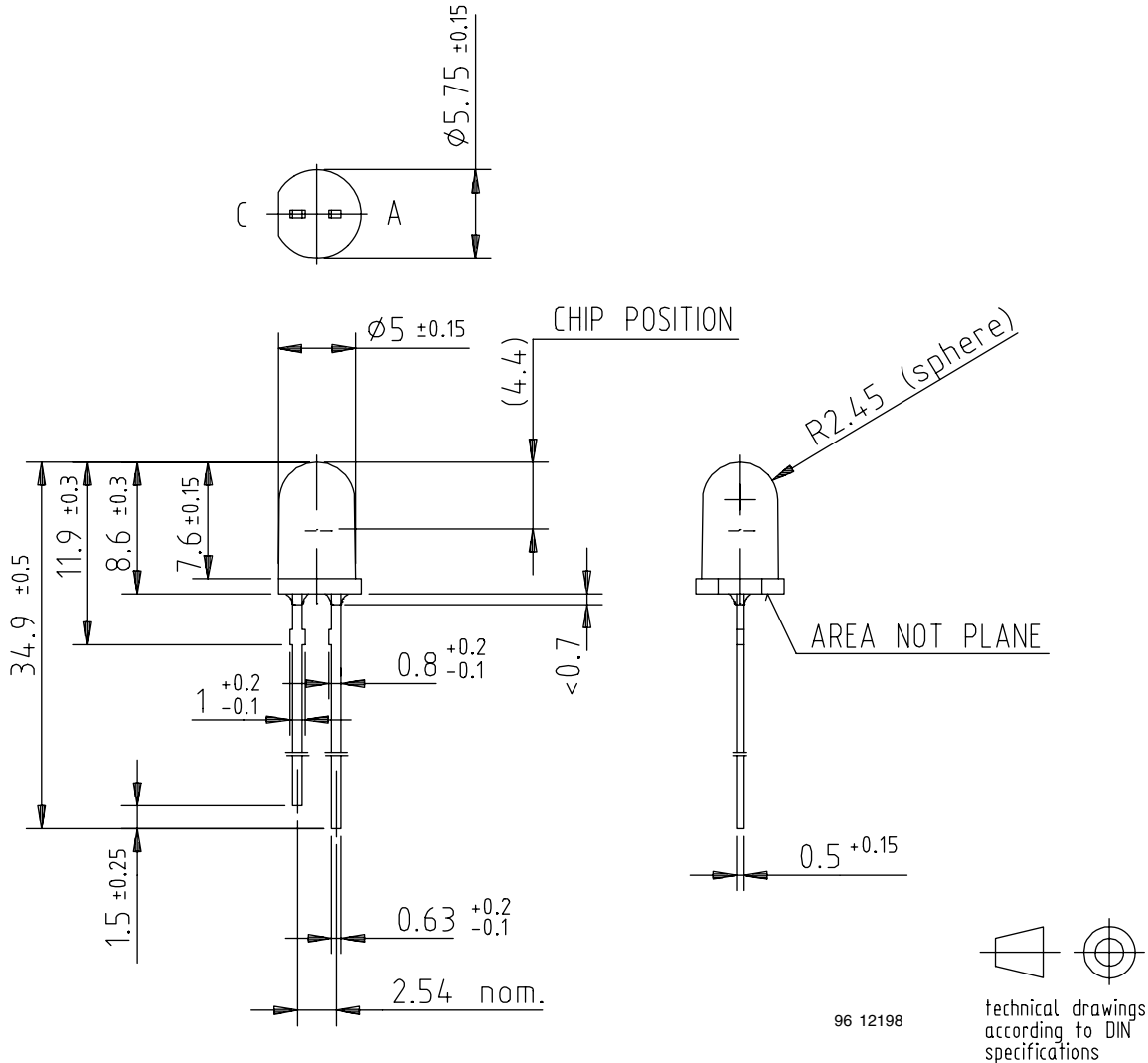


Fig. 5 - Diode Capacitance vs. Reverse Voltage



**PACKAGE DIMENSIONS** in millimeters





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